

HN62428 Series

Preliminary

T-46-13-15

8M (512K x 16-bit) and (1M x 8-bit) Mask ROM

■ DESCRIPTION

The Hitachi HN62428 Series is an 8-Megabit CMOS Mask Programmable Read Only Memory organized either as 524,288 x 16-bit or as 1,048,576 x 8-bit.

The low power consumption of this device makes it ideal for battery powered, portable systems. In addition, the high density and high speed provide enough capacity and high performance to be used as a character generator in laser printers.

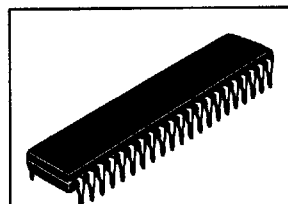
Hitachi's HN62428 is offered with JEDEC-Standard pinouts in 42-pin Plastic DIP and 44-lead Plastic SOP packages. The HN62428 is also packaged in a 44-lead QFP and a 48-lead Plastic SOP.

■ FEATURES

- Single Power Supply
 $V_{cc} = 5V \pm 10\%$
- Fast Access Times:
150 ns/200 ns (max)
- Low Power Consumption:
Active Current: 100 mW (typ)
Standby Current: 5 μ W (typ)
- User Selectable Organization:
1M x 16-bit (Word-Wide)
2M x 8-bit (Byte-Wide)
Switchable with BHE pin
- TTL-Compatible Inputs and Outputs
- Three-State Data Outputs
- Pin Arrangements:
JEDEC Standard Word-Wide/Byte-Wide Pinout
- Packages:
42-pin Plastic DIP
44-lead Plastic QFP
44-lead Plastic SOP
48-lead Plastic SOP

■ ORDERING INFORMATION

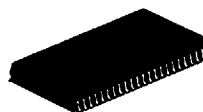
Type No.	Access Time	Package
HN62428P-15	150 ns	42-pin Plastic DIP
HN62428P-20	200 ns	(DP-42)
HN62428FP-15	150 ns	44-lead Plastic QFP
HN62428FP-20	200 ns	(FP-44A)
HN62428F-15	150 ns	48-lead Plastic SOP
HN62428F-20	200 ns	(FP-48DA)
HN62428FB-15	150 ns	44-lead Plastic SOP
HN62428FB-20	200 ns	(FP-44D)



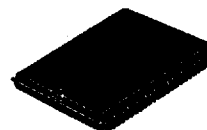
(DP-42)



(FP-44A)



(FP-44D)



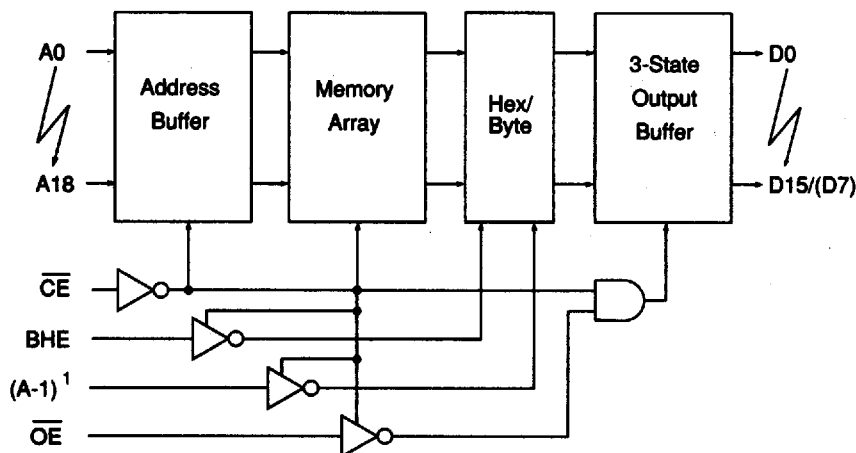
(FP-48DA)

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■ PIN DESCRIPTION

Pin Name	Function
$A_0 - A_{18}$	Address
A_{-1}	Address (Word-Wide)
$D_0 - D_{15}$	Output
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
BHE	Byte Enable
V_{cc}	Power Supply
V_{ss}	Ground
NC	No Connection

■ BLOCK DIAGRAM



(BD.HN62428)

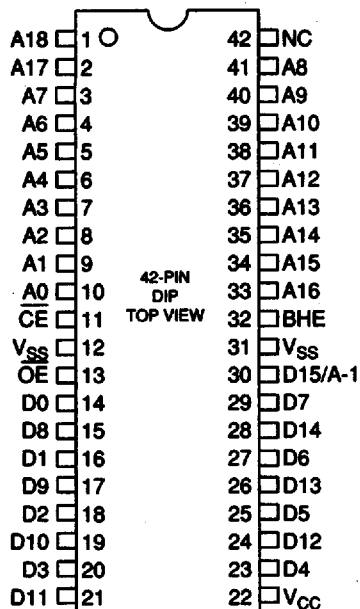
- Notes: 1. * : A_{-1} is the Least Significant Address bit in Byte-Wide Mode.
 2. $BHE = V_{IH}$: 16-bit ($D_{15} - D_0$)
 $BHE = V_{IL}$: 8-bit ($D_7 - D_0$)
 When BHE is low, $D_{14} - D_8$ are in high impedance states.

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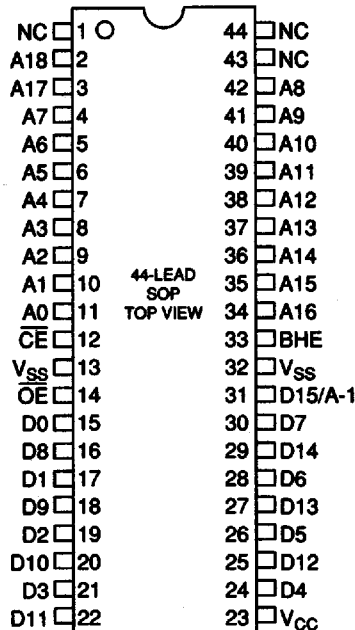
■ PIN ARRANGEMENT

HN62428P Series



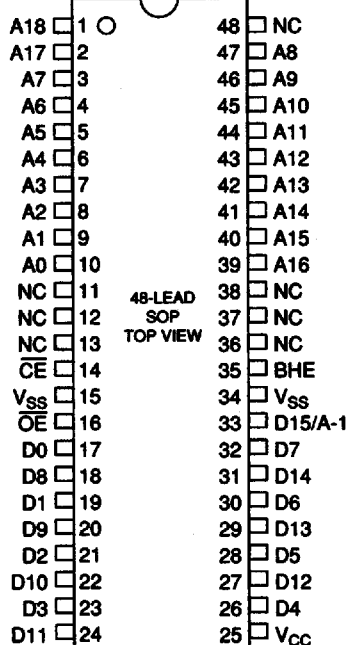
(PinD42.HN62428)

HN62428FB Series



(PinD44.HN62428)

HN62428F Series



Note:

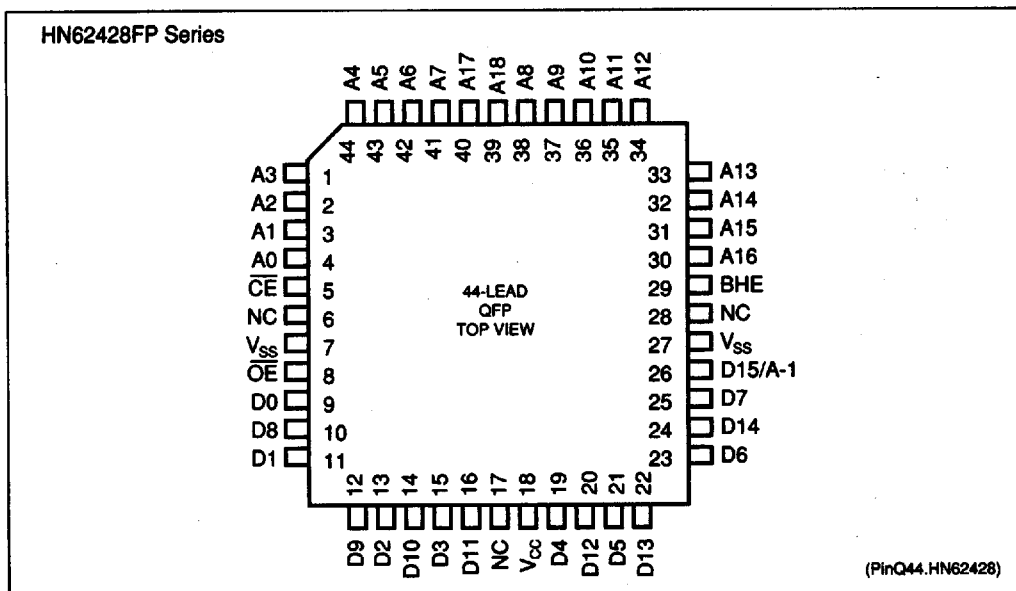
Pins 11, 12, 13, 36, 37 and 38 are connected to the inner lead frame.

(PinT248.HN62428)

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■ PIN ARRANGEMENT (cont.)

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■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Value	Unit
Supply Voltage ¹	V_{CC}	-0.3 to +7.0	V
All Input and Output Voltage ¹	V_I	-0.3 to $V_{CC} + 0.3$	V
Operating Temperature Range	T_{OPR}	0 to +70	°C
Storage Temperature Range	T_{STG}	-55 to +125	°C
Temperature Under Bias	T_{BIAS}	-20 to +85	°C

Notes: 1. With respect to V_{SS} .

■ CAPACITANCE

 $(V_{CC} = 5V \pm 10\%, V_{SS} = 0V, T_a = 25^\circ C, V_{IN} = 0V, f = 1MHz)$

Item	Symbol	Min.	Max.	Unit
Input Capacitance ¹	C_{IN}	-	15	pF
Output Capacitance ¹	C_{OUT}	-	15	pF

Notes: 1. This parameter is sampled and not 100% tested.

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■ DC ELECTRICAL CHARACTERISTICS FOR READ OPERATION

(V_{CC} = 5V ± 10%, V_{SS} = 0 V, T_a = 0 to 70°C)

Item	Symbol	Min.	Max.	Unit	Test Condition
Input Leakage Current	I _I	-	10	μA	V _{IN} = 0 to V _{CC}
Output Leakage Current	I _{LO}	-	10	μA	$\overline{CE}$ = 2.2 V, V _{OUT} = 0 to V _{CC}
Operating V _{CC} Current	I _{CC}	-	50	mA	V _{CC} = 5.5 V, I _{DOUT} = 0 mA, t _{RC} = Min.
Standby V _{CC} Current	I _{SB}	-	30	μA	V _{CC} = 5.5 V, $\overline{CE}$ ≥ V _{CC} -0.2V
Input Voltage	V _{IH}	2.2	V _{CC} +0.3	V	
	V _{IL}	-0.3	0.8	V	
Output Voltage	V _{OH}	2.4	-	V	I _{OH} = -205 μA
	V _{OL}	-	0.4	V	I _{OL} = 1.6 mA

■ AC ELECTRICAL CHARACTERISTICS FOR READ OPERATION

(V_{CC} = 5V ± 10%, V_{SS} = 0 V, T_a = 0 to 70°C)

Test Conditions

- Input pulse levels: 0.8 V / 2.4 V
- Input rise and fall times: ≤10 ns
- Output load: 1 TTL Gate + CL = 100 pF (Including jig capacitance)
- Input/Output Timing Reference level: 1.5 V

Item	Symbol	HN62428-15		HN62428-20		Unit
		Min.	Max.	Min.	Max.	
Read Cycle Time	t _{RC}	150	-	200	-	ns
Address Access Time	t _{AA}	-	150	-	200	ns
$\overline{CE}$ Access Time	t _{ACE}	-	150	-	200	ns
$\overline{OE}$ Access Time	t _{OE}	-	70	-	70	ns
BHE Access Time	t _{BHE}	-	150	-	200	ns
Output Hold Time from Address Change	t _{DHA}	0	-	0	-	ns
Output Hold Time from $\overline{CE}$	t _{DHC}	0	-	0	-	ns
Output Hold Time from $\overline{OE}$	t _{DHO}	0	-	0	-	ns
Output Hold Time from BHE	t _{DHB}	0	-	0	-	ns
$\overline{CE}$ to Output in High Z	t _{CHZ} ¹	-	70	-	70	ns
$\overline{OE}$ to Output in High Z	t _{OCHZ} ¹	-	70	-	70	ns
BHE to Output in High Z	t _{BHZ} ¹	-	70	-	70	ns
$\overline{CE}$ to Output in Low Z	t _{CLZ}	10	-	10	-	ns
$\overline{OE}$ to Output in Low Z	t _{OLZ}	10	-	10	-	ns
BHE to Output in Low Z	t _{BLZ}	10	-	10	-	ns

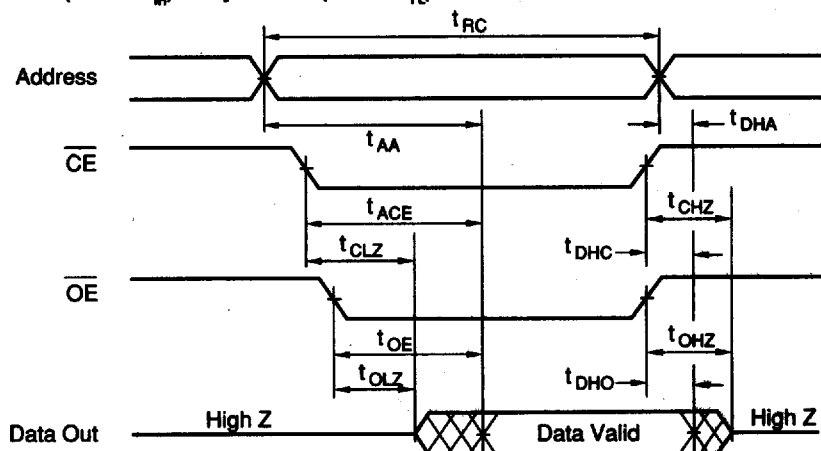
Note: 1. t_{CHZ}¹, t_{OCHZ}¹, and t_{BHZ}¹ define the time at which the output becomes an open circuit and are not referenced to output voltage levels.

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■ READ TIMING WAVEFORM

Word Mode ($BHE = V_{IH}$) or Byte Mode ($BHE = V_{IL}$)

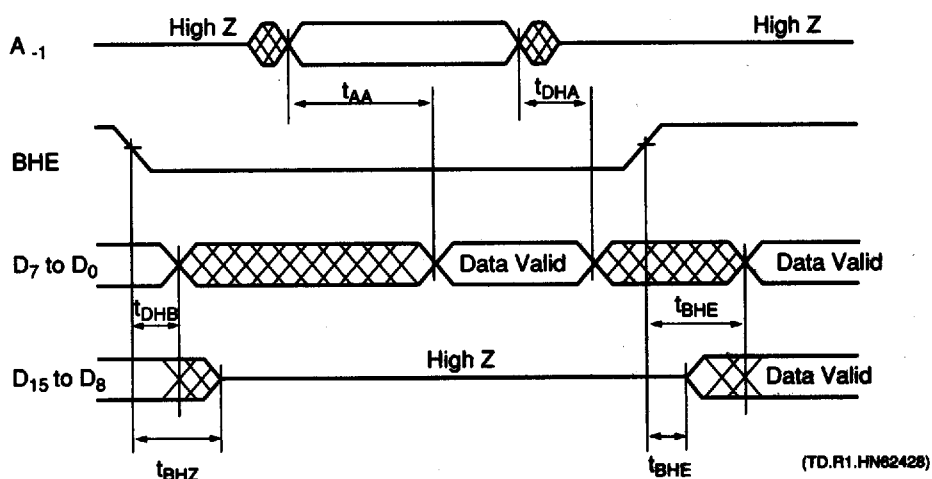
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(TD.R.HN62428)

- Note:
1. t_{DHA} , t_{DHC} , t_{DHO} are determined by the faster time.
 2. t_{AA} , t_{ACE} , t_{OE} are determined by the slower time.
 3. t_{CLZ} , t_{OLZ} are determined by the slower time.

Word Mode/Byte Mode Switch



(TD.R1.HN62428)

- Note:
1. $\overline{CE}$ and $\overline{OE}$ are of select status. A_{16} to A_0 are fixed.
 2. D_{16}/A_{17} terminal is of output state when $BHE = V_{IH}$. $\overline{CE}$ and $\overline{OE}$ are of selected state. At this time, an input signal that is of the inverse phase to the output should not be impressed.

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